

HTH1D12P1K0H(B) 1000W, 960 - 1215 MHz LDMOS Amplifier

Product datasheet

Description

The HTH1D12P1K0H(B) is an unmatched discrete LDMOS Power Amplifier with 1000W saturated output power covering frequency range from 960 - 1215 MHz.

Features

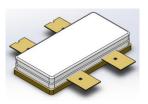
- Operating Frequency Range: 960 -1215MHz
- Operating Drain Voltage: 50V
- Saturation Output Power: 1000W
- Excellent thermal stability due to low thermal resistance package
- Enhanced robustness design without device degradation
- Internally integrated enhanced ESD design

Applications

- Avionics applications in the frequency range of 960 MHz to 1215 MHz
- High efficiency and high power for pulse signal application

Ordering Information

Part Number	Description	
HTH1D12P1K0H(B)	Tray Package	
HTH1D12P1K0H(B) EVB	960-1215 MHz EVB	

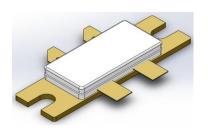


ACC2110S-4L

RoHS

Earless Flanged Balanced
Air Cavity Ceramic Package; 4 Leads

HTH1D12P1K0H

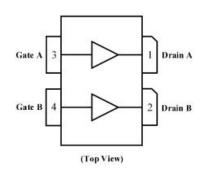


ACC2110B-4L



Flanged Balanced
Air Cavity Ceramic Package; 4 Leads,
2 Mounting holes

HTH1D12P1K0HB



Note: Exposed backside of the package is the source terminal for the transistor

Pin Connections

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Typical Performance

RF Characteristics (Pulse)

Freq (MHz)	P1dB (dBm)	Eff (%)@P1dB	Gain (dB)	P3dB (dBm)	Eff(%)@P3dB
960	58.87	56.97	21.72	60.38	65.11
1130	58.75	57.05	21.05	60.00	62.75
1215	58.95	55.49	21.06	59.87	62.03

 $Test\ conditions\ unless\ otherwise\ noted:\ 25\ ^{\circ}C,\ VDD=+50Vdc,\ IDQ=100mA\ ,\ \ Pulse\ Width=100us,\ Duty\ Cycle=10\%\ test\ on\ WATECH\ Application\ Board$

Absolute Maximum Ratings

Parameter	Range/Value	Unit
Drain voltage (VDSS)	0 to 150	V
Gate voltage (V _{GS})	-10 to 2	V
Storage Temperature (Tstg)	-55 to 150	°C
Junction Temperature (T _J)	225	°C

Electrical Specification

DC Characteristics (Carrier)

Parameter	Conditions	Min	Тур	Max	Unit
Breakdown Voltage V(BR)DSS	Vgs=-8V, Ids=120mA	150	-	-	V
Gate-Source Threshold Voltage VGS(th)	Vds=10V, Ids=120mA	-3.6	-2.8	-2.0	V
Drain Leakage Current loss	Vgs=-10V, Vds=50V	-	0.48	-	mA
Gate Leakage Current Igss	Vgs=-10V, Vds=0V	-	36	-	uA

DC Characteristics (Peak)

Parameter	Conditions	Min	Тур	Max	Unit
Breakdown Voltage V(BR)DSS	Vgs=-8V, Ids=120mA	150	-	-	V
Gate-Source Threshold Voltage Vgs(th)	Vds=10V, Ids=120mA	-3.6	-2.8	-2.0	V
Drain Leakage Current loss	Vgs=-10V, Vds=50V	-	0.48	-	mA
Gate Leakage Current Igss	Vgs=-10V, Vds=0V	-	36	-	uA



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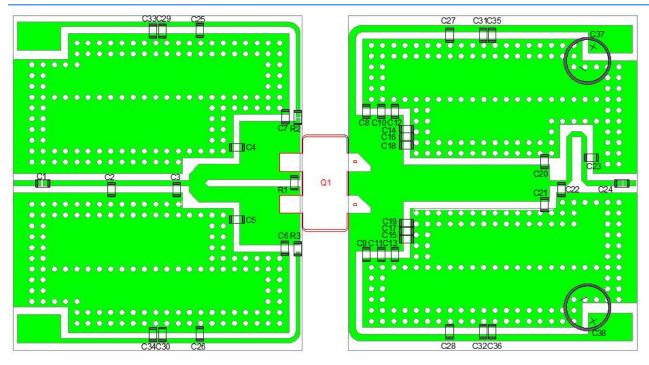
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Condition	Test Result
VSWR=10:1, at all Phase Angles, V_{DD} = +50Vdc, I_{DQ} = 100mA,	No Dovice
10% Pulse PAVG = 1000W, Frequency 1215MHz test on WATECH Application	No Device
Board	Degradation

Thermal Information

Parameter Condition		Value (Typ)	Unit
Thermal Resistance	TCASE= 26.8° C, $V_{DD} = +50$ Vdc, $I_{DQ} = 100$ mA,		
Junction to Case (RTH)	PAVG = 59.7 dBm (933W),	0.31	°C /W
Junction to Case (Kih)	10% pulse signal		

HTH1D12P1K0H(B) 960 - 1215 MHz Reference Design



EVB Layout



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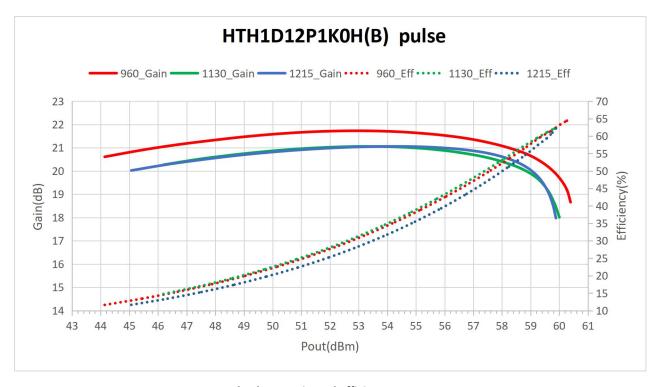
Bill of Materials (BoM) - HTH1D12P1K0H(B)

960 - 1215 MHz Reference Design

Reference	Value	Description	Manufacturer	P/N
		1000W,		
Q1	-	960 - 1215MHz	Watech	HTH1D12P1K0H(B)
		GaN PA		
C1,C25,C26	56pF	MLCC	Murata	GRM21A5C2E560FW01
C2,C14~C17,C20 ~C23	1.0pF	MLCC	Murata	GRM21A5C2E1R0FW01
C3	5.6pF	MLCC	Murata	GRM21A5C2E5R6FW01
C4,C5,C8~C11	4.3pF	MLCC	Murata	GRM21A5C2E4R3FW01
C6,C7	6.2pF	MLCC	Murata	GRM21A5C2E6R2FW01
C12,C13	3.3pF	MLCC	Murata	GRM21A5C2E3R3FW01
C18,C19	2.2pF	MLCC	Murata	GRM21A5C2E2R2FW01
C27,C28	22pF	MLCC	Dalicap	DLC70B220JW501XT
C24	100pF	MLCC	Dalicap	DLC70B101JW501XT
C29~C32	1000pF	MLCC	Dalicap	DLC70B102JW501XT
R1,R2,R3	10Ω	Chip Resistor	КОА	SMD 1206
C33~C36	4.7uF	MLCC	YAGEO	CC1210KKX5R9BB475
C37,C38	1000uF	AEC	Chongx VEHT	100V 18*35mm
РСВ	Rogers 4350B (er = 3.5), thickness = 20 mil (0.508 mm); thickness copper plating = 35 μ m , gold plated $_{\circ}$			

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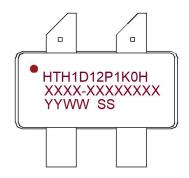
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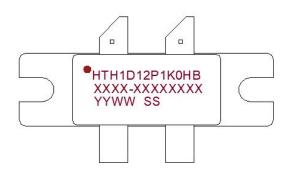


Pulsed CW, Gain and Efficiency vs Pout

 $Test\ conditions\ unless\ otherwise\ noted:\ 25\ ^\circ C,\ VDD=+50Vdc,\ IDQ=\ 100mA\ ,\ Pulse\ Width=\ 100us,\ Duty\ Cycle=\ 10\%\ test\ on\ WATECH\ Application\ Board$

Package Marking and Dimensions





- Line1 (fixed): Device name in work order
- Line2 (unfixed): Mark Lot number in work order (Sample: E596-EERA0001)
- Line3 (unfixed): Date Code + "SS" (The last two digits of sub lot Number)

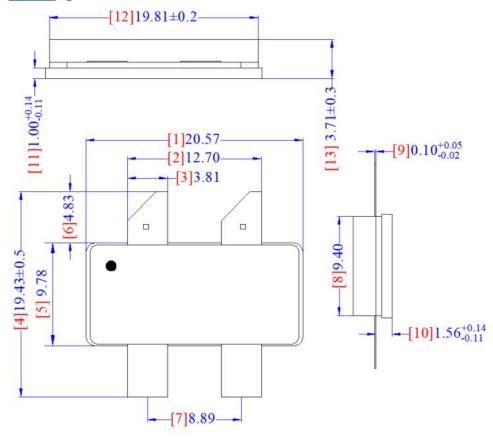
This Marking SPEC only stipulates the content of Marking. For marking requirements such as font and size, please refer to the latest version of "Watech Product Printing Specification"

Marking



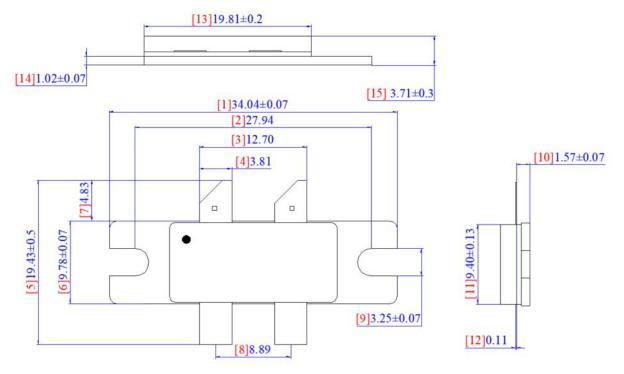
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Remark: 1.Unit: mm; 2.Unlabeled tolerance is \pm 0.13mm.

ACC2110S-4L; Earless Flanged Balanced Air Cavity Ceramic Package; 4 Leads



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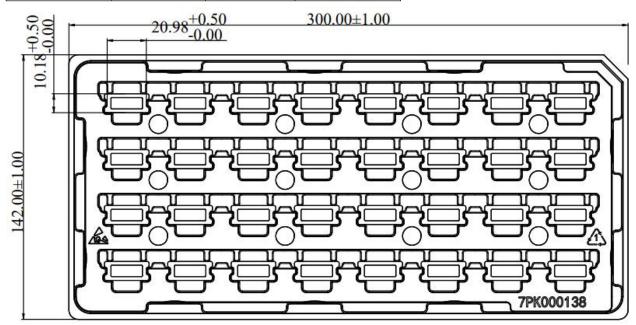
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ACC2110B-4L; Flanged Balanced Air Cavity Ceramic Package; 2 Mounting holes, 4 Leads
Package Dimensions

Tape and Reel Information

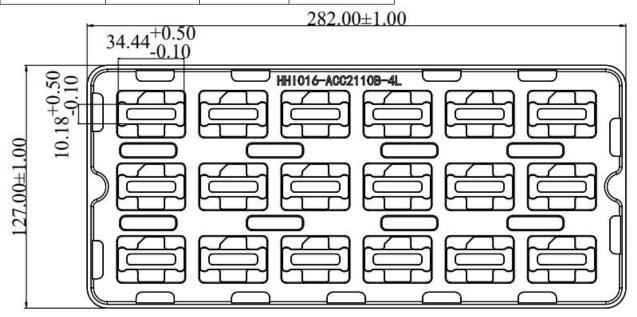
HTH1D12P1K0H:

Package Type	Qty/Tray(pcs)	Qty/Box(pcs)	Qty/Carton(pcs)	
ACC2110S-4L	32	160	960	



HTH1D12P1K0HB:

Package Type	Qty/Tray(pcs)	Qty/Box(pcs)	Qty/Carton(pcs)
ACC2110B-4L	18	90	540



Tray Packaging Descriptions



1000W, 960 - 1215 MHz LDMOS Amplifier

Handling Precautions

Parameter	Grade
Moisture Sensitivity Level MSL	3

Parameter	Rating	Standard
ESD – Human Body Model (HBM)	Class 1B	JESD22-A114
ESD – Me Model (MM)	Class A	EIA/JESD22-A115
ESD – Charged Device Model (CDM)	Class III	JESD22-C101



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RoHS Compliance

This product is compliant with the 2011/65/EU RoHS directive (Restrictions on the Use of Certain Hazardous Substances in Electrical and Electronic Equipment), as amended by Directive 2015/863/EU.

Datasheet Status

Document status	Product status	Definition
Objective Datasheet	Design simulation	Product objective specification
Preliminary Datasheet	Customer sample	Engineering samples and first test results
Product Datasheet	Mass production	Final product specification

Abbreviations

Acronym	Definition	
LDMOS	Laterally-Diffused Metal-Oxide Semiconductor	
CW	Continuous Waveform	

Revision history

Document ID	Datasheet Status	Release Date	Revision Version
Rev 1.0	Product	March 2023	Product version datasheet



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For the latest specifications, additional product information, worldwide sales and distribution locations and information about WATECH:

• Web: <u>www.watechelectronics.com</u>

• Email: MKT@huatai-elec.com

For technical questions and application information:

Email: MKT@huatai-elec.com

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